

# LN172

## GaAlAs Infrared Light Emitting Diode

For optical control systems

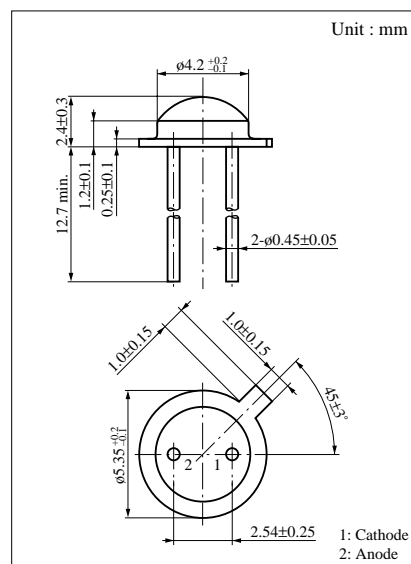
### ■ Features

- High-power output, high-efficiency :  $P_O = 12 \text{ mW}$  (typ.)
- Light emitting spectrum suited for silicon photodetectors :  
 $\lambda_P = 900 \text{ nm}$  (typ.)
- Good optical power output linearity with respect to input current
- Wide directivity :  $\theta = 100 \text{ deg.}$  (typ.)
- Long lifetime, high reliability

### ■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

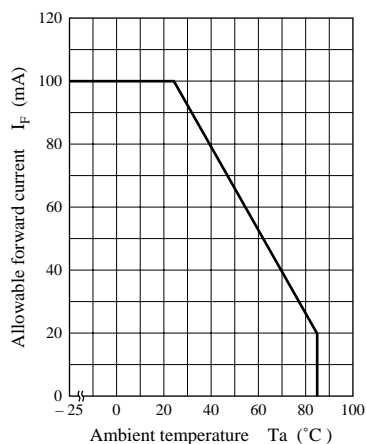
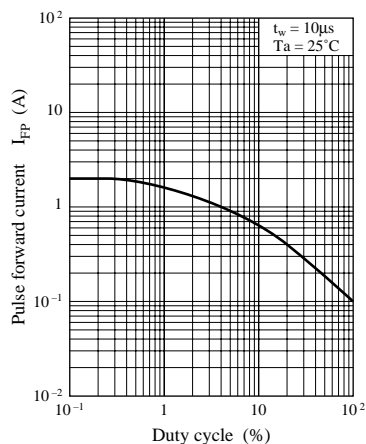
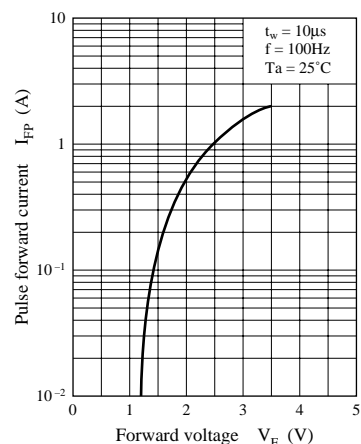
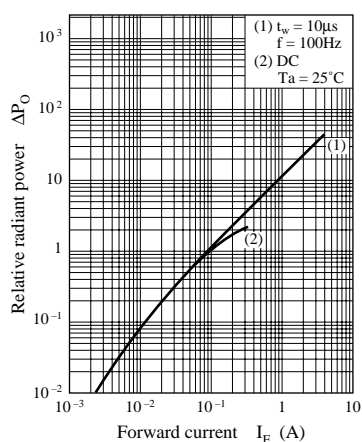
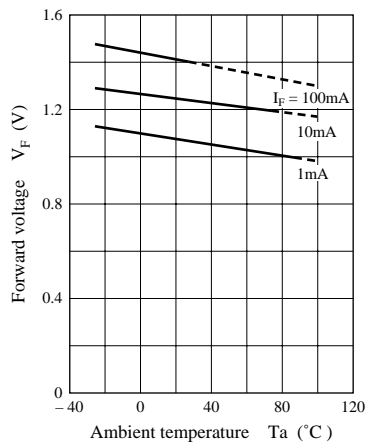
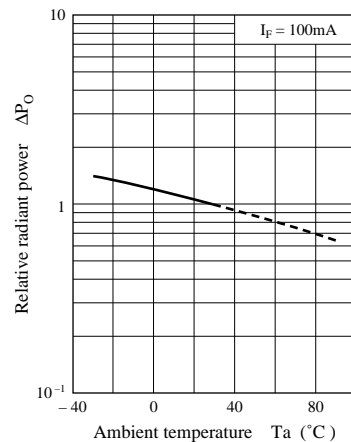
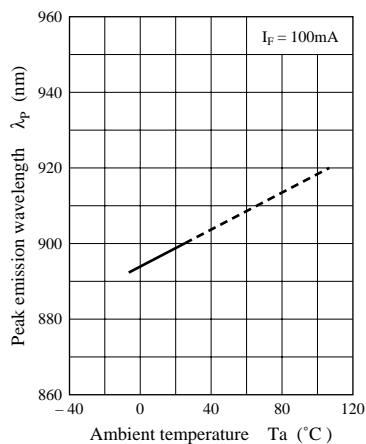
Parameter	Symbol	Ratings	Unit
Power dissipation	$P_D$	170	mW
Forward current (DC)	$I_F$	100	mA
Pulse forward current	$I_{FP}^*$	2	A
Reverse voltage (DC)	$V_R$	3	V
Operating ambient temperature	$T_{opr}$	-25 to +85	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-30 to +100	$^\circ\text{C}$

\*  $f = 100 \text{ Hz}$ , Duty cycle = 0.1 %

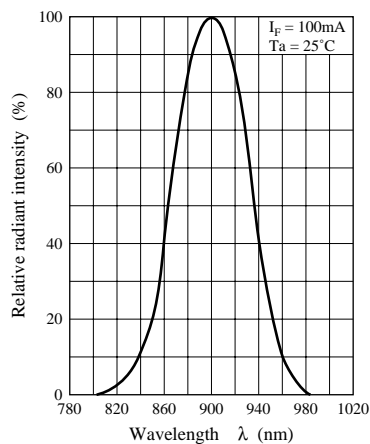


### ■ Electro-Optical Characteristics ( $T_a = 25^\circ\text{C}$ )

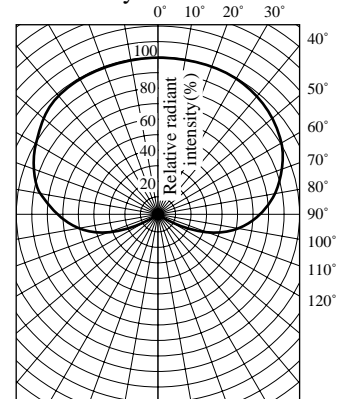
Parameter	Symbol	Conditions	min	typ	max	Unit
Radiant power	$P_O$	$I_F = 100\text{mA}$	7	12		mW
Peak emission wavelength	$\lambda_P$	$I_F = 100\text{mA}$		900		nm
Spectral half band width	$\Delta\lambda$	$I_F = 100\text{mA}$		70		nm
Forward voltage (DC)	$V_F$	$I_F = 100\text{mA}$		1.4	1.7	V
Reverse current (DC)	$I_R$	$V_R = 3\text{V}$			10	$\mu\text{A}$
Capacitance between pins	$C_t$	$V_R = 0\text{V}$ , $f = 1\text{MHz}$		50		pF
Response time	$t_r$ , $t_f$	$I_F = 100\text{mA}$		700		ns
Half-power angle	$\theta$	The angle in which radiant intensity is 50%		100		deg.

$I_F - T_a$  $I_{FP} - \text{Duty cycle}$  $I_{FP} - V_F$  $\Delta P_O - I_F$  $V_F - T_a$  $\Delta P_O - T_a$  $\lambda_p - T_a$ 

Spectral characteristics



Directivity characteristics



# Caution for Safety

 **DANGER**

Gallium arsenide material (GaAs) is used in this product.

Therefore, do not burn, destroy, cut, crush, or chemically decompose the product, since gallium arsenide material in powder or vapor form is harmful to human health.

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